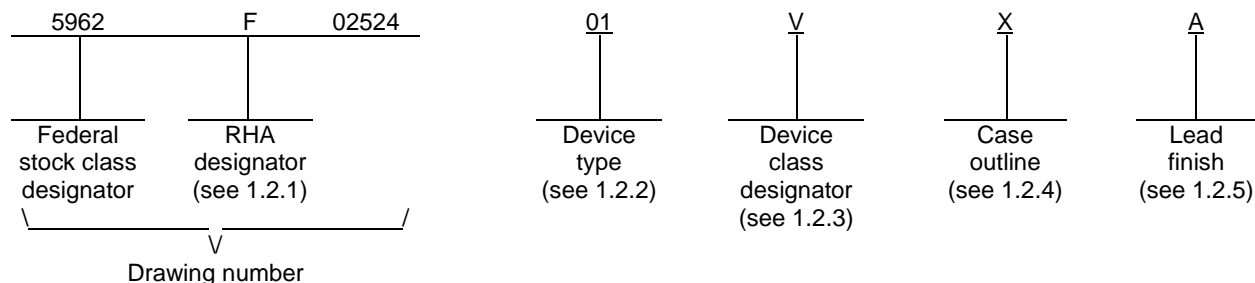


REVISIONS																					
LTR	DESCRIPTION										DATE (YR-MO-DA)				APPROVED						
A	Change to footnote 5/ in 1.3. Added footnote 4/ to K _{VI} test in table I. Made correction to figure 3. -rrp										03-02-19				R. Monnin						
B	Add 3.1.1 and die appendix A. -rrp										05-01-27				R. Monnin						
C	Add low dose rate radiation note to 1.5. -rrp										06-04-17				R. Monnin						
D	Make change to low dose rate radiation note in 1.5. Deleted Non-Government publications paragraph in section 2 and in Appendix A. Revise footnote 3/ as specified under table I. Deleted accelerated aging test paragraph 4.4.4.1.1. -rrp										06-11-28				R. Monnin						
E	Add device type 03. Add case outline U. Make changes to 1.2.2, 1.2.4, 1.3, 1.5, table I, figure 1, and figure 2. -rrp										08-02-11				R. Heber						
F	For figure 1, case outline U, correct dimension A. - drw										12-11-06				Charles F. Saffle						
G	Make corrections to the Quiescent current (ON state) test as specified under Table I. Under the fourth test condition, delete I _{OUT} = 300 mA and substitute 1 A. Under the device type column, delete device type 02. For subgroup 1, delete 25 mA and substitute 60 mA. For subgroup 2, delete 20 mA and substitute 40 mA. For subgroup 3, delete 40 mA and substitute 100 mA. - ro										13-03-27				C. Saffle						
REV																					
SHEET																					
REV	G	G	G	G	G	G	G														
SHEET	15	16	17	18	19	20	21														
REV STATUS				REV				G	G	G	G	G	G	G	G	G	G	G	G	G	
OF SHEETS				SHEET				1	2	3	4	5	6	7	8	9	10	11	12	13	14
PMIC N/A				PREPARED BY Rajesh Pithadia								DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil									
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Rajesh Pithadia																	
				APPROVED BY Raymond Monnin								MICROCIRCUIT, LINEAR, POSITIVE, ADJUSTABLE, LOW DROPOUT, VOLTAGE REGULATOR, MONOLITHIC SILICON									
				DRAWING APPROVAL DATE 03-01-06																	
				REVISION LEVEL G								SIZE A	CAGE CODE 67268	5962-02524							
SHEET 1 OF 21																					

1. SCOPE

1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following example:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device types. The device types identify the circuit function as follows:

Device type	Generic number	Circuit function
01	RH-L4913-ADJ	Radiation hardened, positive, adjustable, 2 A, low dropout voltage regulator with inhibit acces
02	RH-L4913-ADJ	Radiation hardened, positive, adjustable, 1 A, low dropout voltage regulator with inhibit acces
03	RH-L4913-ADJ	Radiation hardened, positive, adjustable, 3 A, low dropout voltage regulator with inhibit acces

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation
Q or V	Certification and qualification to MIL-PRF-38535

1.2.4 Case outlines. The case outlines are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
X	CDFP4-F16	16	Flat pack 1/
Y	See figure 1	14	Dual flat pack with gullwing leads
Z	See figure 1	14	Flat pack
U	See figure 1	5	Bottom terminal chip carrier

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V.

1/ AIN ceramic header with metalized bottom side and pullback of 0.01 x 0.02 inches.

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1.3 Absolute maximum ratings. 2/

DC input voltage	14 V
Output current:	
Case X	2 A
Cases Y and Z	1 A
Case U	3 A
Power dissipation at $T_A = 25^\circ\text{C}$:	
Case X	1 W <u>3/</u>
Cases Y and Z	0.8 W <u>3/</u>
Case U	1.5 W <u>3/</u>
Power dissipation at $T_C = 25^\circ\text{C}$:	
Cases X and U	15 W
Cases Y and Z	3 W
Thermal resistance, junction-to-case (θ_{JC}):	
Cases X and U	8.3°C/W
Cases Y and Z	42°C/W
Thermal resistance, junction-to-ambient (θ_{JA}):	
Case X	125°C/W
Cases Y and Z	156°C/W
Case U	83°C/W
Storage temperature range	-65°C to +150°C
Operating temperature range	-55°C to +150°C
Lead temperature (soldering, 10 seconds)	+300°C <u>4/</u>
Maximum junction temperature (T_J)	+150°C <u>5/</u>

1.4 Recommended operating conditions.

Input voltage range (V_{IN})	3 V to 12 V
Output voltage range (V_{OUT})	1.23 V to 9 V
Ambient operating temperature range (T_A)	-55°C to +125°C

1.5 Radiation features.

Maximum total dose available (dose rate = 50 - 300 rads(Si)/s):	
Device types 01, 02, and 03	300 krad(Si)
Latch-up	<u>6/</u>

The Radiation Hardness Assurance (RHA) devices specified on this drawing have been characterization tested for Enhanced Low Dose Rate Sensitivity (ELDRS). The characterization has been performed at a Low Dose Rate (LDR) of approximately 40 mrads/s and a High Dose Rate (HDR) of 50-300 rad/s. The post-irradiation parametric values for LDR and HDR samples were within the parametric limits as specified in Table I. Characterization testing was performed to the Total Dose level as specified above [300 krad(Si)]. Therefore, the RHA devices on this drawing have been shown not to exceed specification limits at a dose rate of 40 mrads/s at 300 krad(Si). Future testing of the devices on this drawing may therefore be performed at HDR only. Changes to the RHA product listed in this drawing that may affect the RHA response will require analysis to determine whether further characterization for LDR sensitivity is required. The RHA part numbers specified herein that were previously tested at HDR will not be changed based on this characterization testing.

2/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

3/ At $T_A < +25^\circ\text{C}$ without heatsink.

4/ Distance of not less than 1.5 mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.

5/ Internally limited to +175°C by thermal shut down circuit.

6/ No SEL nor SEU effect detected during irradiation with particles of LET = 68 MeV/cm²mg.

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2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <https://assist.dla.mil/quicksearch/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 as specified herein, or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.1.1 Microcircuit die. For the requirements of microcircuit die, see appendix A to this document.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V.

3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein and figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Block diagram. The block diagram shall be as specified on figure 3.

3.2.4 Radiation exposure circuit. The radiation exposure circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing and acquiring activity upon request.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/, 2/, 3/ -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Output voltage	V _{OUT}	V _{OUT} +2.5 V < V _{IN} < 12 V, I _{OUT} = 400 mA	1, 2, 3	01, 02, 03	1.19	1.27	V
		V _{OUT} +2.5 V < V _{IN} < 12 V, I _{OUT} = 1 A		01, 03	1.19	1.27	
Line regulation 4/	K _{VI}	V _{OUT} +2.5 V < V _{IN} < 12 V, I _{OUT} = 5 mA	1	01, 02,		0.35	%
			2, 3	03		0.4	
Load regulation	K _{VO}	V _{IN} = V _{OUT} + 2.5 V, 5 mA < I _{OUT} < 400 mA	1	01, 02,		0.3	%
			2, 3	03		0.5	
		V _{IN} = V _{OUT} + 2.5 V, 5 mA < I _{OUT} < 1 A	1	01, 03		0.5	
			2, 3			0.6	
Quiescent current (ON state)	I _q	I _{OUT} = 5 mA, V _{IN} = V _{OUT} + 2.5 V	1	01, 02, 03		6	mA
			1			8	
			2			8	
		I _{OUT} = 30 mA, V _{IN} = V _{OUT} + 2.5 V	3			14	
			1			25	
			2			20	
		I _{OUT} = 300 mA, V _{IN} = V _{OUT} + 2.5 V	3			40	
			1	01, 03		60	
			2			40	
			3			100	
		I _{OUT} = 1 A, V _{IN} = V _{OUT} + 2.5 V	1	03		150	
			2				
			3				
Quiescent current (OFF state)	I _{qOFF}	V _{INH} > 2.4 V, V _{IN} = V _{OUT} + 2 V	1,2,3	01, 02, 03		1	mA
Dropout voltage	V _d	I _{OUT} = 400 mA, +2.5 V < V _{OUT} < +9 V	1	01, 02,		0.45	V
			2	03		0.55	
			3			0.4	
		I _{OUT} = 1 A, +2.5 V < V _{OUT} < +9 V	1	01, 03		0.65	
			2			0.8	
			3			0.55	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued.

Test	Symbol	Conditions <u>1/</u> , <u>2/</u> , <u>3/</u> $-55^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Inhibit voltage	V _{INHON}	V _{IN} = V _{OUT} + 2.5 V,	1, 2, 3	01, 02,		0.8	V
	V _{INHOFF}	I _{OUT} = 5 mA		03	2.4		
Supply voltage rejection <u>5/</u>	SVR	V _{IN} = V _{OUT} + 2.5 V, I _{OUT} = 5 mA, f = 120 Hz, T _A = +25°C	4	01, 02, 03	60		dB
		V _{IN} = V _{OUT} + 2.5 V, I _{OUT} = 5 mA, f = 33 kHz, T _A = +25°C			30		
Inhibit propagation <u>5/</u> delay	t _{PLH}	V _{INHIBIT} = 2.4 V, V _{OUT} = 3 V, I _{OUT} = 400 mA,	9	01, 02, 03		20	μs
	t _{PHL}	V _{IN} = V _{NOM} + 2.5 V, see figure 4				100	

1/ Device types 01, 02, and 03 have been characterized through all levels M, D, P, L, R, F of irradiation. However, this device is tested at the “F” level. Pre and Post irradiation values are identical unless otherwise specified in table I.

When performing post irradiation electrical measurements for any RHA level, T_A = +25°C.

2/ V_{IN} = V_{OUT} + 2.5 V, T_A = 25°C, C_{IN} = 1 μF, C_{OUT} = 1 μF.

3/ These parts have been characterization tested at low dose rate, see 1.5.

4/ $K_{VI} = (V_{rline}) \times 100 / V_{OUT1}$ where $V_{rline} = V_{OUT1} - V_{OUT'1}$,
V_{OUT1} = V_{OUT} when V_{IN} = V_{NOM} + 2.5 V and I_{OUT} = 5 mA,
V_{OUT'1} = V_{OUT} when V_{IN} = V_{MAX} = 12 V and I_{OUT} = 5 mA

5/ Controlled via design or process and is not directly tested. Characterized on initial design release and upon design or process changes which affect this parameter.

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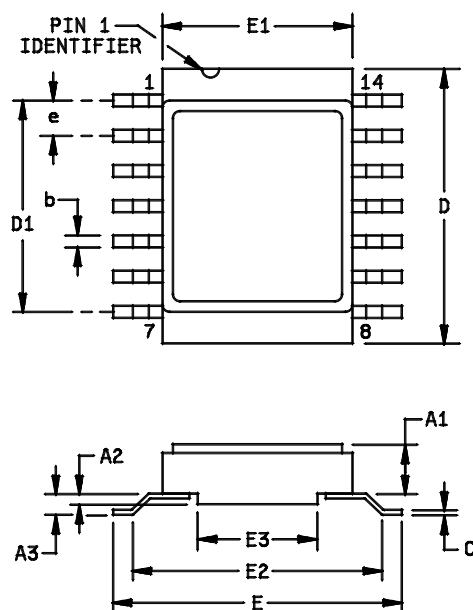
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Case Y



Symbol	Inches		Millimeters		Note
	Min	Max	Min	Max	
A1	.058	.077	1.49	1.95	
A2	.013	.017	0.33	0.43	
A3	.023	.035	0.60	0.90	
b	.015	.019	0.38	0.48	
C	.004	.007	0.102	0.152	
D	.384	.399	9.76	10.14	
D1	.295	.305	7.50	7.75	
E	.394	.419	10.00	10.65	
E1	.266	.278	6.75	7.06	
E2	.354 BSC		9.00 BSC		
E3	.170 BSC		4.31 BSC		
e	.050 BSC		1.27 BSC		
N	14		14		1

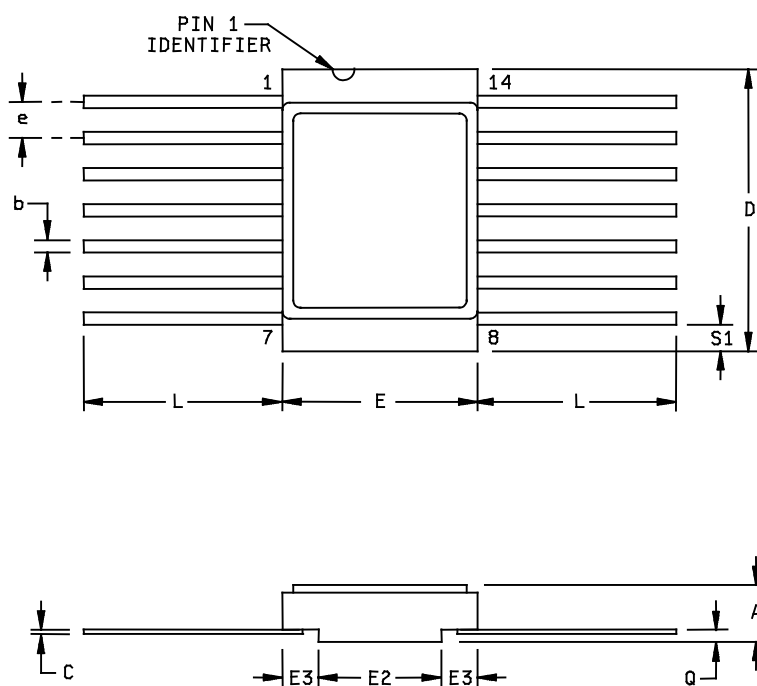
Note:

1. N is the maximum number of terminal positions.
2. The U.S. government preferred system of measurement is the metric SI system. However, since this item was originally designed using inch-pound units of measurement, in the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.

FIGURE 1. Case outlines.

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Case Z



Symbol	Inches		Millimeters		Note
	Min	Max	Min	Max	
A	.077	.091	1.96	2.31	
b	.015	.019	0.38	0.48	
C	.004	.006	0.102	0.152	
D	.384	.399	9.76	10.14	
E	.266	.278	6.75	7.06	
E2	.170 BSC		4.31 BSC		
E3	.030	----	0.76	----	
e	.050 BSC		1.27 BSC		
L	.237	----	6.00	----	
Q	.013	.017	0.33	0.43	
S1	.005	----	0.13	----	
N	14		14		1

Note:

1. N is the maximum number of terminal positions.
2. The U.S. government preferred system of measurement is the metric SI system. However, since this item was originally designed using inch-pound units of measurement, in the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.

FIGURE 1. Case outlines – continued.

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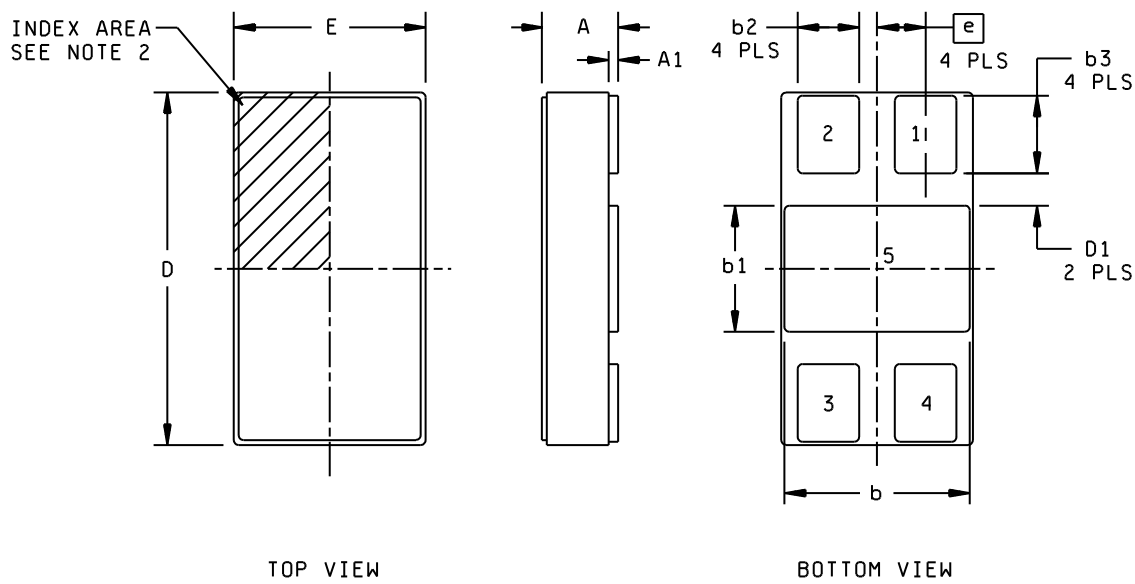
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Case U



Symbol	Inches			Millimeters			Notes
	Min	Typ	Max	Min	Typ	Max	
A	0.112	0.121	0.13	2.84	3.07	3.30	1
A1	0.010	0.015	0.020	0.25	0.38	0.51	
b	0.281	0.286	0.291	7.13	7.26	7.39	
b1	0.195	0.200	0.205	4.95	5.08	5.21	
b2	0.090	0.095	0.100	2.28	2.41	2.54	
b3	0.115	0.120	0.125	2.92	3.05	3.18	
D	0.540	0.545	0.550	13.71	13.84	13.97	
D1	0.030	----	----	0.76	----	----	
E	0.291	0.296	0.301	7.39	7.52	7.65	
e	.075 BSC			1.91 BSC			

NOTES:

1. Measurement prior to solder coating the mounting pads on bottom of package.
2. The terminal #1 identifier must be located within the zone indicated. Details of terminal #1 identifier are optional.
3. The U.S. government preferred system of measurement is the metric SI system. However, since this item was originally designed using inch-pound units of measurement, in the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.

FIGURE 1. Case outline – continued.

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Device type	01	02	03
Case outlines	X	Y and Z	U
Terminal number	Terminal symbol		
1	V _{OUT1}	NC	V _{OUT}
2	V _{OUT1}	V _{OUT1}	ADJ
3	V _{IN}	V _{IN}	INH
4	V _{IN}	NC	V _{IN}
5	V _{IN}	V _{IN}	GND
6	V _{OUT2}	V _{OUT2}	---
7	V _{OUT2}	ISC	---
8	ISC	OCM	---
9	NC	NC	---
10	OCM	NC	---
11	NC	NC	---
12	NC	GND	---
13	GND	INH	---
14	INH	ADJ	---
15	ADJ	---	---
16	NC	---	---

NC = No connect

FIGURE 2. Terminal connections.

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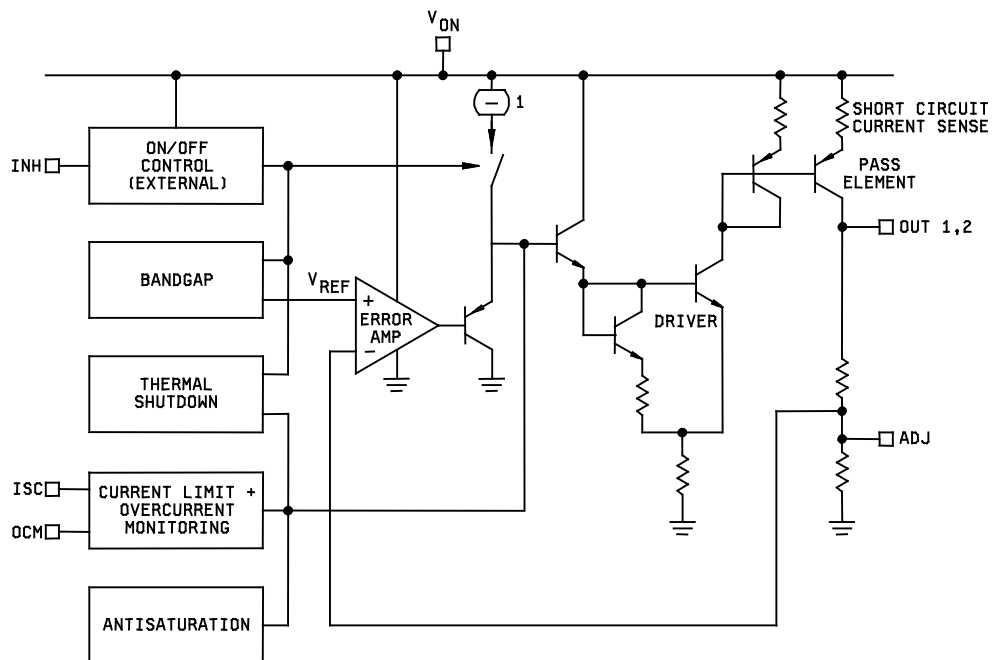


FIGURE 3. Block diagram.

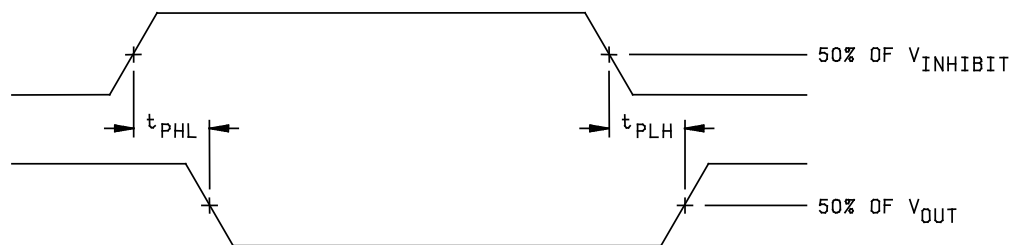


FIGURE 4. Inhibit propagation delay waveform.

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3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 shall be provided with each lot of microcircuits delivered to this drawing.

4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 5, 6, 7, 8, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.

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TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1	1
Final electrical parameters (see 4.2)	1, 2, 3, <u>1/</u> 4, 9	1, 2, 3, <u>1/ 2/</u> 4, 9
Group A test requirements (see 4.4)	1, 2, 3, 4, 9	1, 2, 3, 4, 9
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3 <u>2/</u>
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	1	1

1/ PDA applies to subgroup 1.

2/ Delta limits as specified in table IIB shall be required where specified, and the delta limits shall be computed with reference to the zero hour electrical parameters.

TABLE IIB. Burn-in and operating life test. Delta parameters (+25°C).

Parameters	Symbol	Test Conditions	Delta Limits
Change in output voltage	$\Delta V_{OUT}/V_{OUT}$	$V_{OUT} + 2.5 \text{ V} < V_{IN} < 12 \text{ V}$ at 400 mA	$\pm 1\%$
Change in input regulation coefficient	ΔV_{rline}	$V_{OUT} + 2.5 \text{ V} < V_{IN} < 12 \text{ V}$ at 5 mA	$\pm 6 \text{ mV}$
Change in standby current	$\Delta I_Q/I_Q$	$I_{OUT} = 300 \text{ mA},$ $V_{IN} = V_{OUT} + 2.5 \text{ V}$	$\pm 20\%$ or $\pm 3.5 \text{ mA}$ <u>1/</u>

1/ Whichever is greater.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.2.1 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

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4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes M, Q, and V shall be as specified in MIL-PRF-38535. End-point electrical parameters shall be as specified in table IIA herein.

4.4.4.1 Total dose irradiation testing. Total dose irradiation testing shall be performed in accordance with MIL-STD-883, test method 1019, condition A and as specified herein.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime -VA, telephone (614) 692-8108.

6.4 Comments. Comments on this drawing should be directed to DLA Land and Maritime -VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in MIL-HDBK-103 and QML-38535. The vendors listed in MIL-HDBK-103 and QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime -VA and have agreed to this drawing.

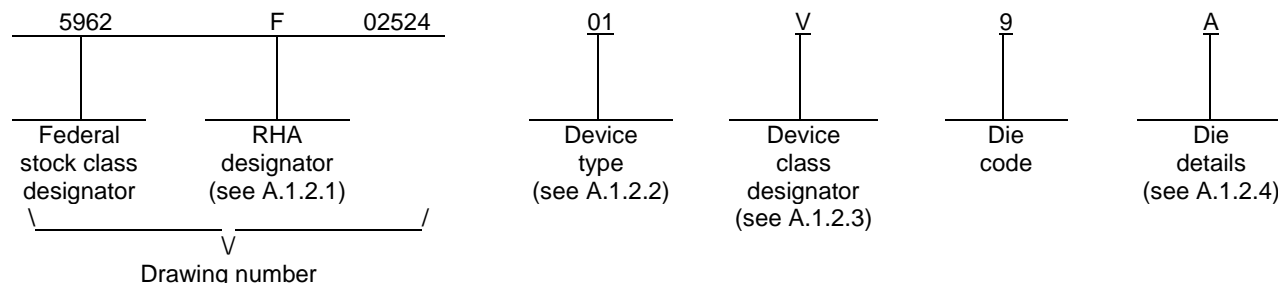
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A.1 SCOPE

A.1.1 Scope. This appendix establishes minimum requirements for microcircuit die to be supplied under the Qualified Manufacturers List (QML) Program. QML microcircuit die meeting the requirements of MIL-PRF-38535 and the manufacturers approved QM plan for use in monolithic microcircuits, multi-chip modules (MCMs), hybrids, electronic modules, or devices using chip and wire designs in accordance with MIL-PRF-38534 are specified herein. Two product assurance classes consisting of military high reliability (device class Q) and space application (device class V) are reflected in the Part or Identification Number (PIN). When available, a choice of Radiation Hardiness Assurance (RHA) levels are reflected in the PIN.

A.1.2 PIN. The PIN is as shown in the following example:



A.1.2.1 RHA designator. Device classes Q and V RHA identified die meet the MIL-PRF-38535 specified RHA levels. A dash (-) indicates a non-RHA die.

A.1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
01	RH-L4913-ADJ	Radiation hardened, positive, adjustable, 2 A, low dropout voltage regulator with inhibit access

A.1.2.3 Device class designator.

<u>Device class</u>	<u>Device requirements documentation</u>
Q or V	Certification and qualification to the die requirements of MIL-PRF-38535

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A.1.2.4 Die details. The die details designation is a unique letter which designates the die's physical dimensions, bonding pad location(s) and related electrical function(s), interface materials, and other assembly related information, for each product and variant supplied to this appendix.

A.1.2.4.1 Die physical dimensions.

<u>Die type</u>	<u>Figure number</u>
01	A-1

A.1.2.4.2 Die bonding pad locations and electrical functions.

<u>Die type</u>	<u>Figure number</u>
01	A-1

A.1.2.4.3 Interface materials.

<u>Die type</u>	<u>Figure number</u>
01	A-1

A.1.2.4.4 Assembly related information.

<u>Die type</u>	<u>Figure number</u>
01	A-1

A.1.3 Absolute maximum ratings. See paragraph 1.3 herein for details.

A.1.4 Recommended operating conditions. See paragraph 1.4 herein for details.

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A.2 APPLICABLE DOCUMENTS.

A.2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARD

MIL-STD-883 - Test Method Standard Microcircuits.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://assist.dla.mil/quicksearch/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

A.2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

A.3 REQUIREMENTS

A.3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

A.3.2 Design, construction and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein and the manufacturer's QM plan for device classes Q and V.

A.3.2.1 Die physical dimensions. The die physical dimensions shall be as specified in A.1.2.4.1 and on figure A-1.

A.3.2.2 Die bonding pad locations and electrical functions. The die bonding pad locations and electrical functions shall be as specified in A.1.2.4.2 and on figure A-1.

A.3.2.3 Interface materials. The interface materials for the die shall be as specified in A.1.2.4.3 and on figure A-1.

A.3.2.4 Assembly related information. The assembly related information shall be as specified in A.1.2.4.4 and on figure A-1.

A.3.2.5 Radiation exposure circuit. The radiation exposure circuit shall be as defined in paragraph 3.2.4 herein.

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A.3.3 Electrical performance characteristics and post-irradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and post-irradiation parameter limits are as specified in table I of the body of this document.

A.3.4 Electrical test requirements. The wafer probe test requirements shall include functional and parametric testing sufficient to make the packaged die capable of meeting the electrical performance requirements in table I.

A.3.5 Marking. As a minimum, each unique lot of die, loaded in single or multiple stack of carriers, for shipment to a customer, shall be identified with the wafer lot number, the certification mark, the manufacturer's identification and the PIN listed in A.1.2 herein. The certification mark shall be a "QML" or "Q" as required by MIL-PRF-38535.

A.3.6 Certification of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see A.6.4 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply for this appendix shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and the requirements herein.

A.3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 shall be provided with each lot of microcircuit die delivered to this drawing.

A.4 VERIFICATION

A.4.1 Sampling and inspection. For device classes Q and V, die sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modifications in the QM plan shall not affect the form, fit, or function as described herein.

A.4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and as defined in the manufacturer's QM plan. As a minimum, it shall consist of:

- a. Wafer lot acceptance for class V product using the criteria defined in MIL-STD-883, method 5007.
- b. 100% wafer probe (see paragraph A.3.4 herein).
- c. 100% internal visual inspection to the applicable class Q or V criteria defined in MIL-STD-883, method 2010 or the alternate procedures allowed in MIL-STD-883, method 5004.

A.4.3 Conformance inspection.

A.4.3.1 Group E inspection. Group E inspection is required only for parts intended to be identified as radiation assured (see A.3.5 herein). RHA levels for device classes Q and V shall be as specified in MIL-PRF-38535. End point electrical testing of packaged die shall be as specified in table IIA herein. Group E tests and conditions are as specified in paragraphs 4.4.4 and 4.4.4.1 herein.

A.5 DIE CARRIER

A.5.1 Die carrier requirements. The requirements for the die carrier shall be accordance with the manufacturer's QM plan or as specified in the purchase order by the acquiring activity. The die carrier shall provide adequate physical, mechanical and electrostatic protection.

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A.6 NOTES

A.6.1 Intended use. Microcircuit die conforming to this drawing are intended for use in microcircuits built in accordance with MIL-PRF-38535 or MIL-PRF-38534 for government microcircuit applications (original equipment), design applications, and logistics purposes.

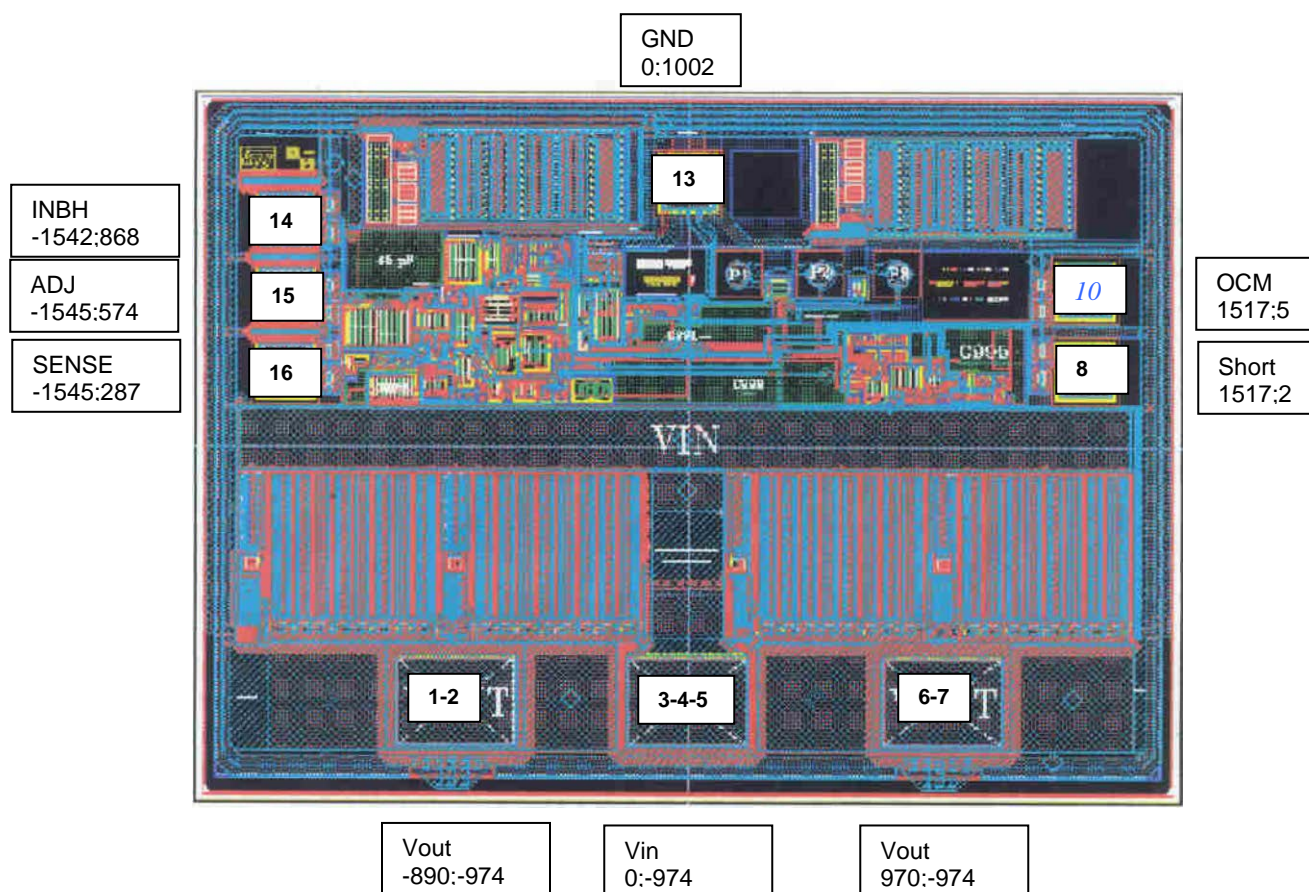
A.6.2 Comments. Comments on this appendix should be directed to DLA Land and Maritime-VA, Columbus, Ohio, 43218-3990 or telephone (614)-692-0540.

A.6.3 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

A.6.4 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in MIL-HDBK-103 and QML-38535. The vendors listed within MIL-HDBK-103 and QML-38535 have submitted a certificate of compliance (see A.3.6 herein) to DLA Land and Maritime-VA and have agreed to this drawing.

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NOTE: Pad numbers reflect terminal numbers when placed in case outline X (see figure 2).

FIGURE A-1. Die bonding pad locations and electrical functions.

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Die bonding pad locations and electrical functions

Die physical dimensions.

Die size: 150 mils x 110 mils

Die thickness: $375\text{ }\mu\text{m} \pm 25\text{ }\mu\text{m}$ (14.8 mils \pm 1 mil)

Pad size: V_{IN} , V_{OUT} pads: $450\text{ }\mu\text{m} \times 330\text{ }\mu\text{m}$

Control pads: $184\text{ }\mu\text{m} \times 184\text{ }\mu\text{m}$

Interface materials.

Top metallization: Al/Si/Cu, $1.05\text{ }\mu\text{m} \pm 0.15\text{ }\mu\text{m}$

Backside metallization: None

Glassivation.

Type: P. Vapox + Nitride

Thickness: $0.6\text{ }\mu\text{m} \pm 0.1\text{ }\mu\text{m} + 0.6\text{ }\mu\text{m} \pm 0.08\text{ }\mu\text{m}$

Substrate: Silicon

Assembly related information.

Substrate potential: Floating if tied to V_{SS}

Special assembly instructions: Pad sense not used

FIGURE A-1. Die bonding pad locations and electrical functions – continued.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 13-03-27

Approved sources of supply for SMD 5962-02524 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime -VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <http://www.landandmaritime.dla.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
5962F0252401VXC	F8859	RHFL4913KPA-01V
5962F0252401VXA	F8859	RHFL4913KPA-02V
5962F0252401QXC	F8859	RHFL4913KPA-01Q
5962F0252401QXA	F8859	RHFL4913KPA-02Q
5962F0252401V9A	F8859	L4913ADIE2V
5962F0252402VYC	<u>3/</u>	RHFL4913SOA-03V
5962F0252402VYA	<u>3/</u>	RHFL4913SOA-04V
5962F0252402VZC	<u>3/</u>	RHFL4913KA-05V
5962F0252402VZA	<u>3/</u>	RHFL4913KA-06V
5962F0252403VUC	F8859	RHFL4913SCA-07V

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

Vendor CAGE
number

F8859

Vendor name
and address

STMicroelectronics
3 rue de Suisse
CS 60816
35208 RENNES cedex2-FRANCE

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